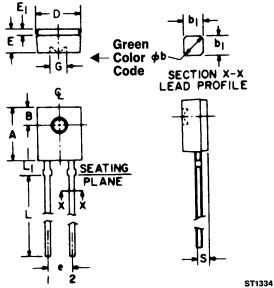


AIGAAS INFRARED EMITTING DIODE

F5G1

PACKAGE DIMENSIONS



1	4 •	2			
SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
Α	5.59	5.80	.220	.228	
В	1.78	NOM.	.070	NOM.	2
®b	.60	.75	.024	.030	1
b,	.51	NOM.	.020	NOM.	1
D	4.45	4.70	.175	.185	
E	2.41	2.67	.095	.105	
Ε,	.58	.69	.023	.027	
е	2.41	2.67	.095	.105	3
	4.00	NON	070	NOM	

DESCRIPTION

The F5G1 is an 880nm LED encapsulated in a clear, wide angle, sidelooker package.

FEATURES

- Good optical to mechanical alignment
- Mechanically and wavelength matched to the L14Q series phototransistor
- Plastic package with a color stripe for easy recognition from phototransistor
- High irradiance level

PACKAGE OUTLINE

.94 .033 .037

.500 1.40 1.65 .055

.065



12.7

- NOTES: 1. TWO LEADS. LEAD CROSS SECTION DIMENSIONS UNCONTROLLED WITHIN 1.27 mm (.050") OF SEATING PLANE.
- 2. CENTERLINE OF ACTIVE ELEMENT LOCATED WITHIN .25 mm (.010") OF TRUE POSITION.

 3. AS MEASURED AT THE SEATING PLANE.
- 4. INCH DIMENSIONS DERIVED FROM MILLIMETERS.



AIGAAS INFRARED EMITTING DIODE

ABSOLUTE MAXIMUM RATINGS (T _a = 25°C Unless Ot	therwise Specified)
Storage Temperature	
Soldering: Lead Temperature (Iron) Lead Temperature (Flow)	
Continuous Forward Current Forward Current (pw, $1\mu S; \leq 33 \text{ Hz}$). Reverse Voltage Power Dissipation	

ELECTRICAL CHARACTERISTICS (T _A = 25°C Unless Otherwise Specified) (All measurements made under pulse conditions.)									
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS			
Forward Voltage	$V_{\scriptscriptstyle F}$	_		1.7	V	$I_F = 20 \text{ mA}$			
Reverse Breakdown Voltage	V _R	6.0			V	I _R = 10 μA			
Reverse Leakage Current	I _R	_		10	μΑ	V _R = 5 V			
Peak Emission Wavelength	λ _p		880		nm	I _F = 100 mA			
Emission Angle at ½ Power	θ		±35		Degrees				
Radiant Intensity	le	0.6		_	mW/sr	I _F = 20 mA ⁽⁶⁾			

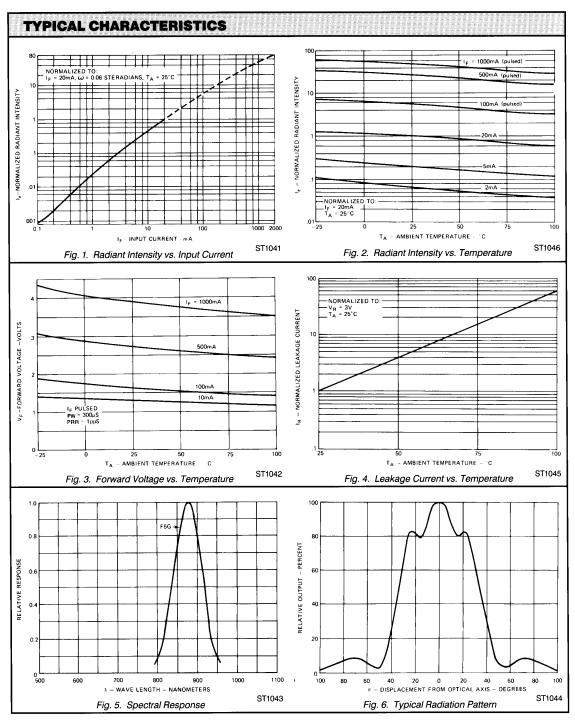
NOTES

- Derate power dissipation linearly 1.33 mW/°C above 25°C ambient.
 RMA flux is recommended.

- HMA flux is recommended.
 Methanol or Isopranol alcohols are recommended as cleaning agents.
 Soldering iron tip ¼s" (1.6 mm) minimum from housing.
 As long as leads are not under any stress or spring tension.
 Ie measured with a 0.45 cm aperture placed 1.6 cm from the tip of the lens on the lens centerline perpendicular to the plane of the leads.



AIGAAS INFRARED EMITTING DIODE





AIGaAs INFRARED EMITTING DIODE

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.